

<b>Notice of References Cited</b>	Application/Control No. 09/414,226	Applicant(s)/Patent Under Reexamination CHANG ET AL.	
	Examiner Donghee Kang	Art Unit 2811	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification	
	A	US-6,180,978-B1	Jan.30,2001	Chatterjee et al.	257	327
	B	US-6,232,188-B1	May.15,2001	Murtaza et al.	438	300
	C	US-6,117,741-A	Sep.12,2000	Chatterjee et al.	438	299
	D	US- -				
	E	US- -				
	F	US- -				
	G	US- -				
	H	US- -				
	I	US- -				
	J	US- -				
	K	US- -				
	L	US- -				
	M	US- -				

**FOREIGN PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification	
	N	- -					
	O	- -					
	P	- -					
	Q	- -					
	R	- -					
	S	- -					
	T	- -					

**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)					
	U	Chatterjee et al., "CMOS metal replacement gate transistors using tantalum pentoxide gate insulator", IEEE IEDM Sep., 1998, pp 777-780.					
	V						
	W						
	X						

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.